

	Type	Hi ts	Search Text	DBs	Time Stamp	Cor ror	E rror
						Com muni	Com muni
						cate nts	cate nts
1	BRS	10	thin adj film near nanowire	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/24 16:00		0
2	BRS	22	nanowire same gate same drain same source and	USPAT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:02		0
3	BRS	14	nanowire same gate same drain same source and diode and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:03		0
4	BRS	35	align\$ nanowire same gate same drain same	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/25 16:54		0
5	BRS	14	align\$ nanowire and gate and (drain or source) and cathode and anode and	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:04		0
6	BRS	45	align\$ and nanowire and (drain or source) and cathode and anode and diode and driver and memory and logic and align\$ and single adj crystal\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:26		0

	Type	Hi ts	Search Text	DBs	Time Stamp	Corr	Conn	Error
7	BRS	1	nano\$ and gate and (drain or source) and cathode and anode and diode and matrix near driv\$ and memory and logic and align\$ and single adj crystal\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:14			0
8	BRS	22	nano\$ not nanometer and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:15			0
9	BRS	22	(nanow\$ or nanos\$ or nanop\$ or nanot\$) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:17			0

	Type	Hi ts	Search Text	DBs	Time Stamp	Com ments	Error s
10	BRS	6	(nanow\$ or nanost\$ or nanop\$ or nanot\$) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:46		0
11	BRS	1	nanos\$ with current and gate and (drain or source) and cathode and anode and diode and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:25		0
12	BRS	31	nano\$ with current and gate and (drain or source) and diode and memory and logic and align\$ and single adj crystal\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:28		0

	Type	Hits	Search Text	DBs	Time Stamp	Correlations	Error Count
13	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:47		0
14	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:48		0
15	BRS	54	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and driv\$ and memory and logic and align\$ and single adj crystals	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:49		0

	Type	Hi ts	Search Text	DBs	Time Stamp	Com ments	E rror s
16	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and (drain or source) and driv\$ and memory and logic and align\$ and single adj crystals	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:51		0
17	BRS	5	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and (drain or source) and memory and logic and align\$ and single adj crystal\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:14		0
18	IS&R	2	("6314019").PN .	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/25 18:08		0
19	BRS	4	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and memory and logic and align\$	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:20		0

			Type Hi ts	Search Text	DBs	Time Stamp	Com m e n t s	Cor r o r D e f e r e n c e i t i o n s	Error s
20	BRS	35	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and aligns		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:21			0
21	BRS	13	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and memory and aligns		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:04			0
22	BRS	2	(nanowire or nanostructure or nanoparticle or nanotube) near channel and gate and drain and source and memory and aligns		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:06			0
23	BRS	24	(nanowire or nanostructure or nanoparticle or nanotube) near channel and gate and drain and source		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:06			0